# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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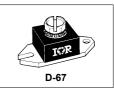


## International **1©R** Rectifier

#### SCHOTTKY RECTIFIER

### 123NQ... (R) SERIES

#### 120 Amp



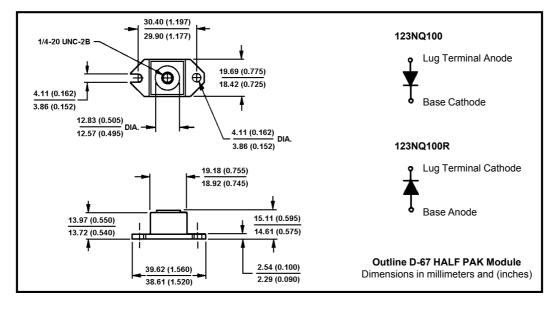
#### **Major Ratings and Characteristics**

Cha	racteristics	123NQ(R)	Units
I <sub>F(AV)</sub>	Rectangular waveform	120	A
V <sub>RRM</sub>	range	80 to 100	V
I <sub>FSM</sub>	@tp=5µssine	16,000	А
V <sub>F</sub>	@120Apk,T <sub>J</sub> =125°C	0.74	V
Τ <sub>J</sub>	range	- 55 to 175	°C

#### **Description/Features**

The 123NQ... (R) high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 175° C T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces two parallel DO-5's
- Easier to mount and lower profile than DO-5's
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



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#### 123NQ...(R) Series

#### Bulletin PD-2.250 rev. C 05/02

## International **tor** Rectifier

#### Voltage Ratings

Part number	123NQ080	123NQ090	123NQ100
V <sub>R</sub> Max. DC Reverse Voltage (V)	22	90	100
V <sub>RWM</sub> Max. Working Peak Reverse Voltage (V)	80		

#### Absolute Maximum Ratings

	Parameters	123NQ	Units	Conditions	
I <sub>F(AV)</sub>	Max. Average Forward Current *See Fig. 5	120	A	50% duty cycle @ $T_c = 121^\circ C$ , r	ectangular wave form
I <sub>FSM</sub>	Max. Peak One Cycle Non-Repetitive	16,000	•	5µs Sine or 3µs Rect. pulse	Following any rated load condition and
	Surge Current * See Fig. 7	2100	A	10ms Sine or 6ms Rect. pulse	with rated V <sub>RRM</sub> applied
E <sub>AS</sub>	Non-RepetitiveAvalancheEnergy	15	mJ	$T_J = 25 \degree C, I_{AS} = 1 \text{ Amps}, L = 30 \text{ mH}$	
I <sub>AR</sub>	RepetitiveAvalancheCurrent	1	A	Current decaying linearly to zero in 1 µsec	
				Frequency limited by $T_J$ max. $V_{\mu}$	=1.5 x V <sub>R</sub> typical

#### **Electrical Specifications**

	Parameters		Units	Conditions	
V <sub>FM</sub>	Max. Forward Voltage Drop (1)	0.91	V	@ 120A	T - 25°C
	* See Fig. 1	1.08	V	@ 240A	T <sub>J</sub> = 25 °C
		0.74	V	@ 120A	T <sub>1</sub> = 125 °C
		0.88	V	@ 240A	1 <sub>J</sub> = 125 O
I <sub>RM</sub>	Max. Reverse Leakage Current (1)	3	mA	T <sub>J</sub> = 25 °C	V = rated V
	* See Fig. 2	40	mA	Т <sub>Ј</sub> = 125 °С	$V_R = rated V_R$
C <sub>T</sub>	Max. Junction Capacitance	2650	pF	$V_{R} = 5V_{DC}$ , (test signal range 100Khz to 1Mhz) 25 °C	
Ls	Typical Series Inductance	7.0	nH	From top of terminal hole to mounting plane	
dv/dt	Max. Voltage Rate of Change (Rated $V_{P}$ )	10000	V/ µs		

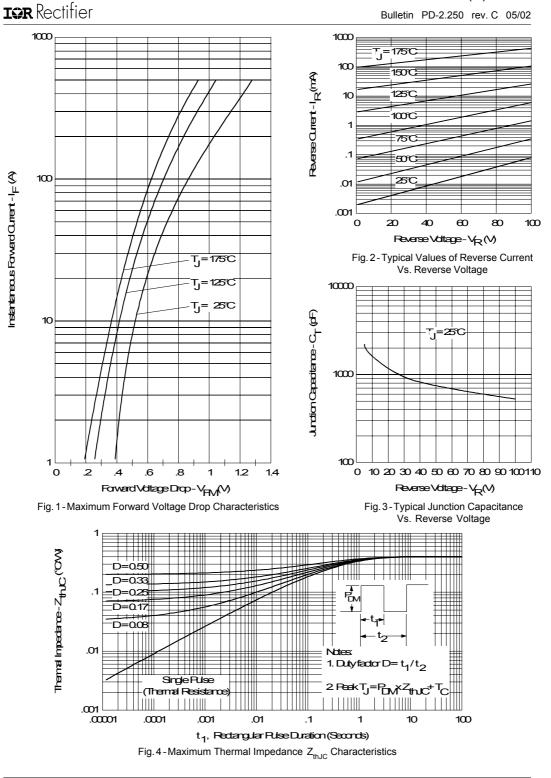
#### **Thermal-Mechanical Specifications**

(1) Pulse Width < 300µs, Duty Cycle < 2%

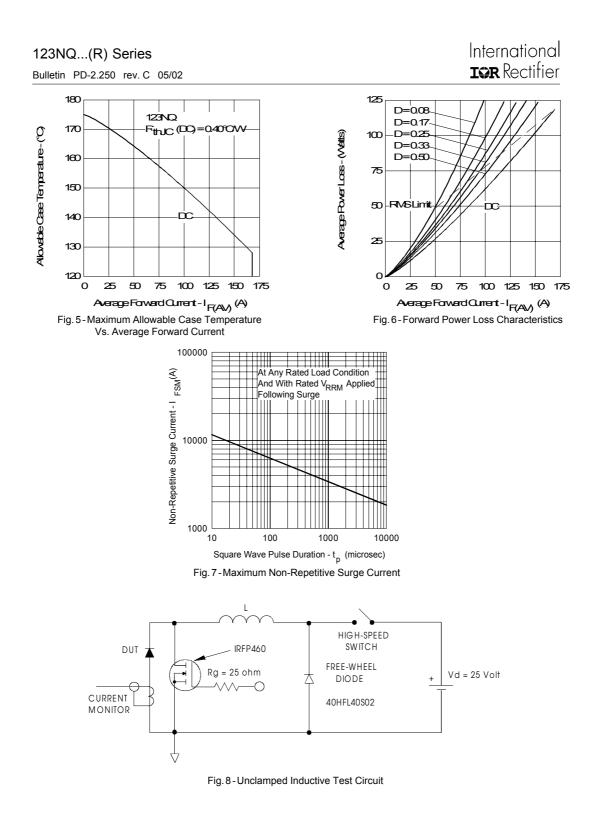
	Parameters		123NQ	Units	Conditions
Т	Max. Junction Temperature Range		-55 to 175	°C	
T <sub>stg</sub>	Max. Storage Temperature Range		-55 to 175	°C	
R <sub>thJC</sub>	Max. Thermal Resistance Junction to Case		0.40	°C/W	DC operation *See Fig. 4
R <sub>thCS</sub>	S Typical Thermal Resistance, Case to Heatsink		0.15	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		25.6(0.9)	g(oz.)	
Т	MountingTorque	Min.	40 (35)		Non-lubricated threads
		Max.	58 (50)	Kg-cm	
	Terminal Torque	Min.	58(50)	(lbf-in)	
		Max.	86(75)		
	CaseStyle			K Modu	le

International

#### 123NQ...(R) Series



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International	123NQ(R) Series
<b>IPR</b> Rectifier	Bulletin PD-2.250 rev. C 05/02

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web site.



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